NSN 5962-01-467-3528

Memory Microcircuit - Page 1 of 1



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Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
E-3a awacs, rsip ppl
Features Provided:
Dynamic and monolithic
Inclosure Configuration:
Dual-in-line
Product Name:
Microcircuit, memory, digital, cmos 256k x 4 dynamic random access memory (dram), monolithic silicon
Voltage Rating And Type Per Characteristic:
0.0 volts input and 7.0 volts input
Memory Device Type:
Ram
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
20 printed circuit
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A458a0